

11MHz CMOS Rail-to-Rail IO Opamps

Features

Single-Supply Operation from +2.1V ~ +5.5V

• Rail-to-Rail Input / Output

Gain-Bandwidth Product: 11MHz (Typ.)

Low Input Bias Current: 1pA (Typ.)

Low Offset Voltage: 3.5mV (Max.)

High Slew Rate: 9V/μs

Settling Time to 0.1% with 2V Step: 0.3µs

Low Noise: 8nV/ Hz @10kHz

• Quiescent Current: 1.1mA per Amplifier (Typ.)

Operating Temperature: -40°C ~ +125°C

Small Package:

LMV721 Available in SOT23-5, SC70-5, SOP-8 and MSOP-8 Packages

LMV722 Available in SOP-8 and MSOP-8 Packages

LMV724 Available in SOP-14 and TSSOP-14 Packages LMV721N Available in SOT23-6 and SC70-6 Packages



Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
LMV721M5/TR	SOT-23-5	V721,LMV721,A30A	REEL	3000pcs/reel
LMV721M7/TR	SC70-5(SOT-353)	V721	REEL	3000pcs/reel
LMV721M/TR	SOP-8	LMV721	REEL	2500pcs/reel
LMV721MM/TR	MSOP-8	V721	REEL	3000pcs/reel
LMV721NM6/TR	SOT-23-6	V721N	REEL	3000pcs/reel
LMV721NM7/TR	SC70-6	V721N	REEL	3000pcs/reel
LMV722M/TR	SOP-8	LMV722	REEL	2500pcs/reel
LMV722MM/TR	MSOP-8	LMV722,V722	REEL	3000pcs/reel
LMV724M/TR	SOP-14	LMV724	REEL	2500pcs/reel
LMV724MT/TR	TSSOP-14	LMV724	REEL	2500pcs/reel



General Description

The LMV72X have a high gain-bandwidth product of 11 MHz, a slew rate of 9V/µs, and a quiescent current of 1.1mA per amplifier at 5V. The LMV721N has a power-down disable feature that reduces the supply current to 90nA. The LMV72X are designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for LMV72X. They are specified over the extended industrial temperature range (-40°C to +125°C). The operating range is from 2.1V to 5.5V. The LMV721 single is available in Green SC70-5, SOT23-5, SOP-8 and MSOP-8 packages. The LMV722 dual is available in Green SOP-14 and TSSOP-14 packages. The LMV721N single with shutdown is available in Green SOT23-6 and SC70-6 packages.

Applications

- Sensors
- Active Filters
- Cellular and Cordless Phones
- Laptops and PDAs

- Audio
- Handheld Test Equipment
- Battery-Powered Instrumentation
- A/D Converters

Pin Configuration

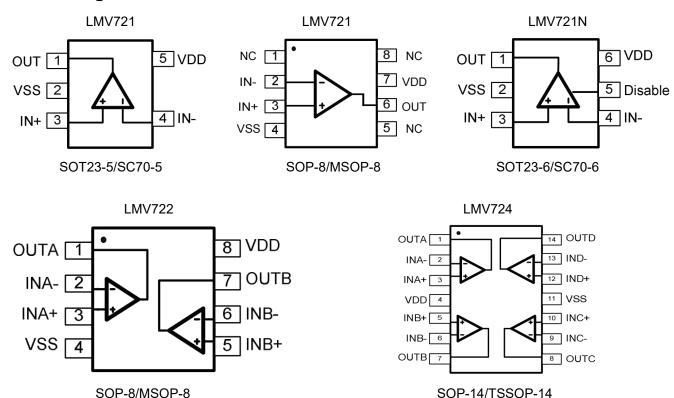


Figure 1. Pin Assignment Diagram



Absolute Maximum Ratings

Condition	Min	Max
Power Supply Voltage (VDD to Vss)	-0.5V	+7.5V
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	VDD+0.5V
PDB Input Voltage	Vss-0.5V	+7V
Operating Temperature Range	-40°C	+125°C
Junction Temperature	-	+160°C
Storage Temperature Range	-55°C	+150°C
Lead Temperature (soldering, 10sec)	-	+260°C
Package Thermal Resistance (TA=+25℃)		
SOP-8, θJA	-	125°C/W
MSOP-8, θJA	-	216°C/W
SOT23-5, θJA	-	190°C/W
SOT23-6, θJA	-	190°C/W
SC70-5, θJA	-	333°C/W
ESD Susceptibility		
НВМ	-	8KV
MM	-	400V

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



Electrical Characteristics

(At Vs=5V, T_A = +25°C, V_{CM} = $V_S/2$, R_L = 600 $_{\Omega}$, unless otherwise noted.)

				LM\	/721/2/4/	′1N		
		TYP	ı	/IN/MAX	OVER	ГЕМРЕР	RATURE	
PARAMETER	CONDITIONS	+25℃	+25 ℃	0℃ to 70℃	-40℃ to 85℃	-40℃ to 125℃	UNITS	MIN / MAX
INPUT CHARACTERISTICS								
Input Offset Voltage (VOS) Input Bias Current (IB) Input Offset Current (IOS) Input Common Mode Voltage Range		0.8 1 1	3.5	3.9	4.3	4.6	mV pA pA	MAX TYP TYP
(VCM)	VS = 5.5V	-0.1 to +5.6					V	TYP
Common Mode Rejection Ratio (CMRR)	VS = 5.5V, VCM = -0.1V to 4V	82	65	64	64	63	dB	MIN
Open-Loop Voltage Gain (AOL)	VS = 5.5V, VCM = -0.1V to 5.6V RL = 600Ω , VO = 0.15V to 4.85V RL = $10k\Omega$, VO = 0.05V to 4.95V	75 90 108	80	76	75	68	dB dB dB	MIN MIN MIN
Input Offset Voltage Drift (ΔVOS/ΔT)		2.4					μV/°C	TYP
OUTPUT CHARACTERISTICS								
Output Voltage Swing from Rail	$R_L = 600\Omega$ $R_L = 10k\Omega$	0.1 0.015					V V	TYP TYP
Output Current (IOUT) Closed-Loop Output Impedance	f = 100kHz, G = 1	70 7.5	55	45	42	38	mA Ω	MIN TYP
POWER-DOWN DISABLE				1				
Turn-On Time Turn-Off Time DISABLE Voltage-Off		1.1 0.3	0.8				μs μs V	TYP TYP MAX
DISABLE Voltage-On			2				V	MIN
POWER SUPPLY				ı	I			
Operating Voltage Range			2.1 5.5	2.1 5.5	2.1 5.5	2.1 5.5	V V	MIN MAX
Power Supply Rejection Ratio (PSRR)	VS = +2.5V to +5.5V	91	74	72	72	68	Db	MIN
Quiescent Current/Amplifier (IQ) Supply Current when Disabled (LMV721N Only)	VCM = (-VS) + 0.5V IOUT = 0	1.1 90	1.5	1.65	1.7	1.85	mA nA	MAX MAX



Electrical Characteristics

(At Vs=5V, TA = +25 $^{\circ}$ C, VCM = VS/2, RL = 600 Ω , unless otherwise noted.)

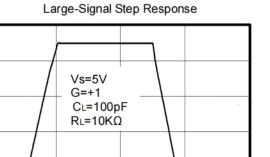
				LN	/IV721/2/4	I/1N				
PARAMETER	CONDITIONS	TYP	MIN/MAX OVER TEMPERATURE							
FARAINETER	CONDITIONS	+25℃	+25 ℃	0℃ to 70℃	-40℃ to 85℃	-40℃to 125℃	UNITS	MIN / MAX		
DYNAMIC PERFORMANCE										
Gain-Bandwidth Product (GBP)	RL = 10kΩ, CL = 100pF	11					MHz	TYP		
Phase Margin (φ _O)	R _L = 10kΩ, C _L = 100pF	51					Degrees	TYP		
Full Power Bandwidth (BWP)	$<$ 1% distortion, RL = 600 Ω	400					kHz	TYP		
Slew Rate (SR)	$G = +1$, 2V Step, $R_L = 10$ kΩ	9					V/µs	TYP		
Settling Time to 0.1% (ts)	G = +1, 2V Step, R _L = $600Ω$	0.3					μs	TYP		
Overload Recovery Time	VIN ·Gain = VS, RL = 600Ω	1.5					μs	TYP		
NOISE PERFORMANCE										
Voltage Noise Density (e _n)	f = 1kHz	11.5					nV /Hz	TYP		
	f = 10kHz	8					nV /Hz	TYP		

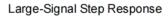


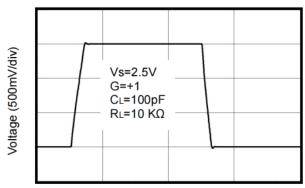
Voltage (1V/div)

Typical Performance characteristics

(At Vs=5V, T_A = +25°C, V_{CM} = Vs/2, R_L = 600 Ω , unless otherwise noted.)



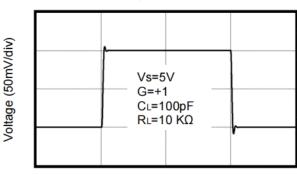




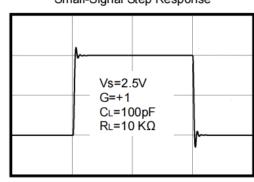
Time (1µs/div)

Time (1µs/div)

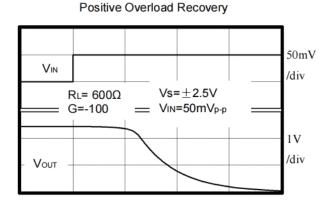




Small-Signal Step Response



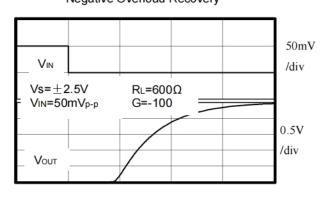
Time (1µs/div)



Time (2µs/div)

Negative Overload Recovery

Time (1µs/div)



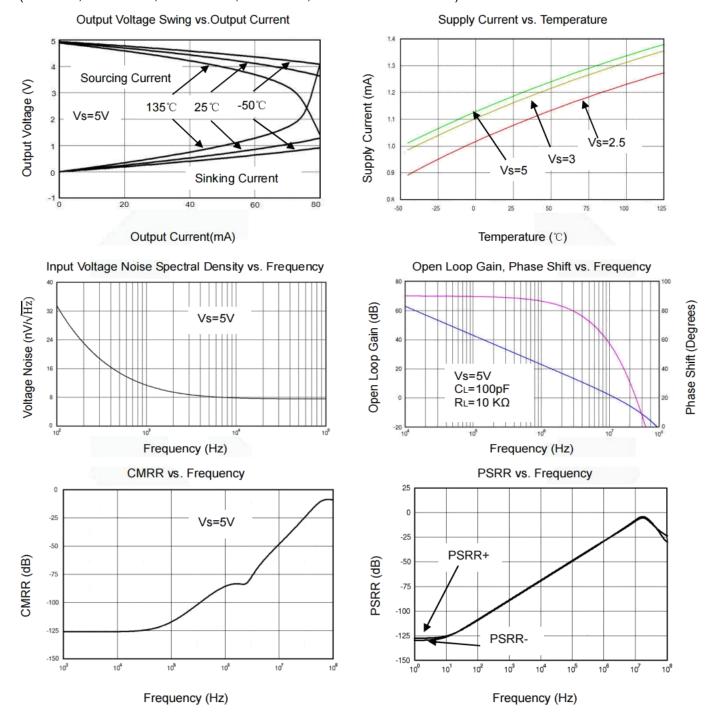
Time (2µs/div)

Voltage (50mV/div)



Typical Performance characteristics

(At Vs=5V, TA = $+25^{\circ}$ C, VCM = VS/2, RL = 600Ω , unless otherwise noted.)





Application Note

Size

LMV72X series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the LMV72X series packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

LMV72X series operates from a single 2.1V to 5.5V supply or dual ± 1.05 V to ± 2.75 V supplies. For best performance, a 0.1 μ F ceramic capacitor should be placed close to the VDD pin in single supply operation. For dual supply operation, both VDD and VSS supplies should be bypassed to ground with separate 0.1 μ F ceramic capacitors.

Low Supply Current

The low supply current (typical 1.1mA per channel) of LMV72X series will help to maximize battery life . They are ideal for battery powered systems

Operating Voltage

LMV72X series operate under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40°C to +125°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime

Rail-to-Rail Input

The input common-mode range of LMV72X series extends 100mV beyond the supply rails (V SS-0.1V to VDD+0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of LMV72X series can typically swing to less than 2mV from supply rail in light resistive loads (>100k Ω), and 15mV of supply rail in moderate resistive loads (10k Ω).

Capacitive Load Tolerance

The LMV72X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain.

Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.



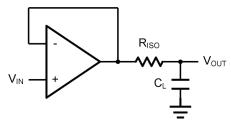


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the RISO resistor value, the more stable VOUT will be. However, if there is a resistive load RL in parallel with the capacitive load, a voltage divider (proportional to RISO/RL) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. RF provides the DC accuracy by feed-forward the VIN to RL. CF and RISO serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of CF. This in turn will slow down the pulse response.

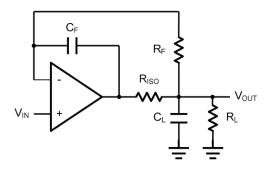


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy



Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using LMV72X.

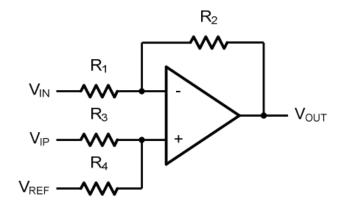


Figure 4. Differential Amplifier

$$V_{OUT} = (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_4}{R_1} V_{IN} - \frac{R2}{R1} V_{IP} + (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_3}{R_1} V_{REF}$$

If the resistor ratios are equal (i.e. R1=R3 and R2=R4), then

$$V_{OUT} = \frac{R_2}{R_1} (V_{IP} - V_{IN}) + V_{REF}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by -R2/R1. The filter has a -20dB/decade roll-off after its corner frequency $fC=1/(2\pi R3C1)$.

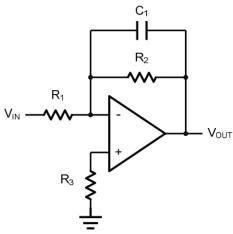


Figure 5. Low Pass Active Filter



Instrumentation Amplifier

The triple LMV72X can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of R2/R1. The two differential voltage followers assure the high input impedance of the amplifier.

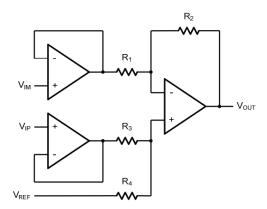
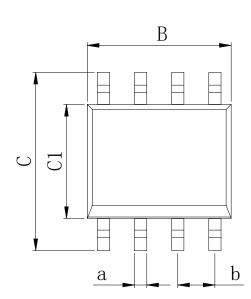
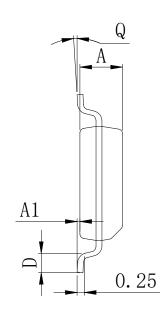


Figure 6. Instrument Amplifier



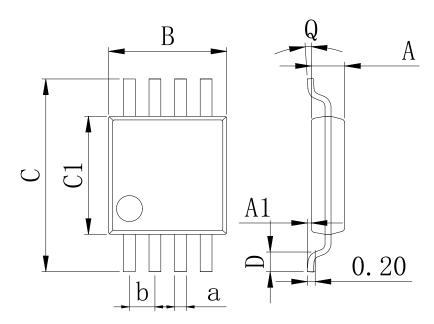
SOP-8





Dimensions In Millimeters(SOP-8)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b		
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC		
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	1.21 030		

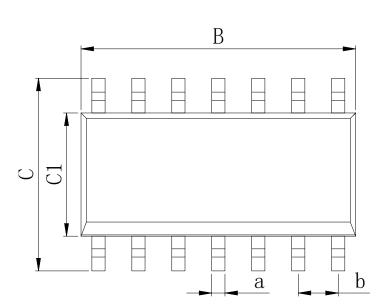
MSOP-8

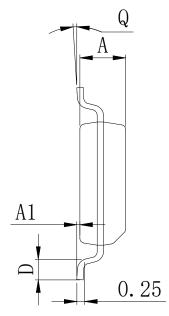


Dimensions In M	Dimensions In Millimeters(MSOP-8)											
Symbol:	Α	A1	В	С	C1	D	Q	а	р			
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC			
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	0.00 630			



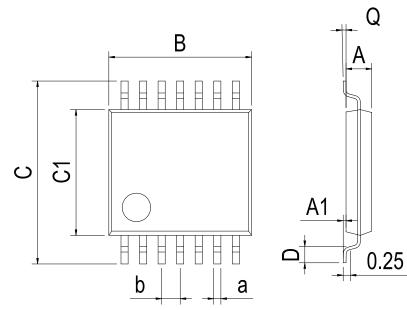
SOP-14





Dimensions In Millimeters(SOP-14)											
Symbol:	А	A1	В	С	C1	D	Q	а	b		
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	1.27 BSC		
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	1.27 BSC		

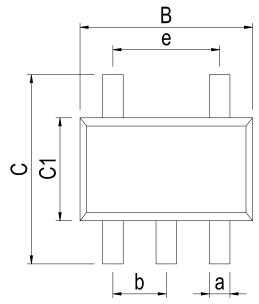
TSSOP-14

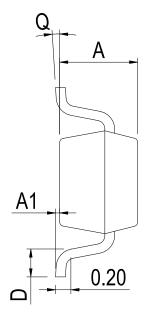


Dimensions In Millimeters(TSSOP-14)										
Symbol:	Α	A1	В	С	C1	D	Q	а	b	
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65.000	
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	0.65 BSC	



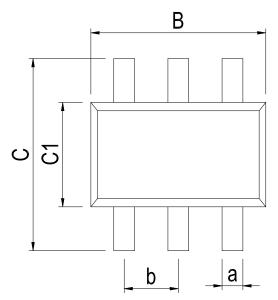
SOT-23-5

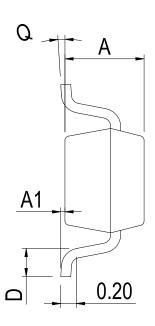




Dimensions In	Dimensions In Millimeters(SOT-23-5)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b	е		
Min:	1.00	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.95 BSC	1.90 BSC		
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.50	0.95 BSC	1.80 050		

SOT-23-6



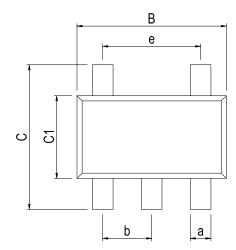


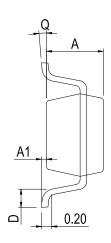
Dimensions In Millimeters(SOT-23-6)										
Symbol:	А	A1	В	С	C1	D	Q	а	b	
Min:	1.00	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.95 BSC	
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.50	0.95 650	

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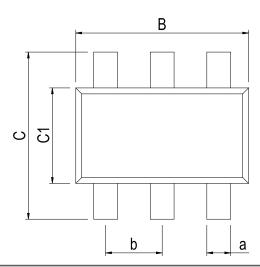
SC70-5

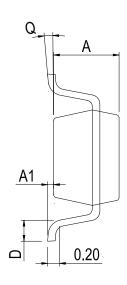




Dimensions In	Dimensions In Millimeters(SC70-5)											
Symbol:	А	A1	В	С	C1	D	Q	а	b	е		
Min:	0.90	0.00	2.00	2.15	1.15	0.26	0°	0.15	0.65	1.30 BSC		
Max:	1.00	0.15	2.20	2.45	1.35	0.46	8°	0.35	BSC	1.30 BSC		

SC70-6





Dimensions In M	Dimensions In Millimeters(SC70-6)											
Symbol:	А	A1	В	С	C1	D	Q	а	b			
Min:	0.90	0.00	2.00	2.15	1.15	0.26	0°	0.15	0.65 BSC			
Max:	1.00	0.15	2.20	2.45	1.35	0.46	8°	0.35	0.00 650			



Revision History

DATE	REVISION	PAGE
2016-7-5	New	1-17
2023-7-20	Update encapsulation type、update sc70-5 and sc70-6 Physical Dimensions	1、15
2024-10-25	Update SOT-23-5 and SOT-23-6 Physical dimension、Update Lead Temperature	14、3

LMV721/22/24/21N

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